Code: 13A04701

B.Tech IV Year I Semester (R13) Supplementary Examinations June 2017

VLSI DESIGN

(Common to ECE & EIE)

Time: 3 hours Max. Marks: 70

PART – A

(Compulsory Question)

1 Answer the following: $(10 \times 02 = 20 \text{ Marks})$

- What is Moore's law? State various IC technologies on the basis of number of transistors on a chip. (a)
- Define threshold voltage with suitable equation of a MOS device. (b)
 - What is the figure of merit of a MOS transistor? Mention the suitable expression for figure of merit. (c)
 - Design a stick diagram for NMOS inverter. (d)
 - Explain working of pass transistor logic. (e)
 - Design a two input CMOS NAND gate with neat sketch. (f)
 - Explain the working of a magnitude comparator. (g)
 - Compare CPLD and FPGA. (h)
 - Write a short note on design capture tools. (i)
 - Explain controllability and observability. (i)

PART - B

(Answer all five units, $5 \times 10 = 50 \text{ Marks}$)

[UNIT - I]

2 Explain NMOS fabrication process flow with neat diagrams.

Draw V-I characteristics of NMOS transistor. Explain its operation. Derive the drain to source current 3 equation in saturation and resistive region.

[UNIT - II]

4 Design a stick and layout diagram for CMOS inverter and two input n-MOS NAND

- 5 (a) Define fan-in and fan-out. Explain their effects on propagation delay.
 - What do you mean by inverter delay? Explain.

[UNIT - III]

6 What are the alternate gate circuits are available, explain them with suitable sketch?

OR

7 Explain about VLSI physical design floor planning.

[UNIT - IV]

8 Implement arithmetic logic unit to perform both arithmetic and logic functions using a full adder.

OR

9 Explain the design flow of FPGA.

UNIT - V

- What is meant by synthesis? Explain the circuit synthesis design methods. 10 (a)
 - (b) What is meant by Simulation? Explain the various VHDL simulations.

Explain various design capture and verification tools. 11